TOSHIBA 1SS360F

TOSHIBA DIODE SILICON EPITAXIAL PLANAR TYPE

1 S S 3 6 0 F

ULTRA HIGH SPEED SWITCHING APPLICATIONS

Small Package : 1608 Flat Lead

Excellent in Forward Current and Forward Voltage $: V_{F(3)} = 0.92 V \text{ (Typ.)}$ Characteristics

 $: t_{rr} = 1.6 \text{ ns (Typ.)}$ Fast Reverse Recovery Time

Small Total Capacitance $: C_T = 2.2 pF (Typ.)$

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum (Peak) Reverse Voltage	V_{RM}	85	V
Reverse Voltage	$V_{\mathbf{R}}$	80	V
Maximum (Peak) Forward Current	I_{FM}	300 (*)	mA
Average Forward Current	IO	100 (*)	mA
Surge Current (10 ms)	I _{FSM}	2 (*)	A
Power Dissipation	P	100	mW
Junction Temperature	T_{j}	125	°C
Storage Temperature Range	$T_{ m stg}$	-55~125	°C

1.6 ± 0.1 0.85 ± 0.1 1. CATHODE1 CATHODE2 3. ANODE **ESM JEDEC** EIAJ **TOSHIBA** 1-2SA1A

Unit in mm

(*) Unit Rating. Total Rating = Unit Rating \times 1.5

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage	$V_{F(1)}$	$I_{\mathbf{F}} = 1 \text{ mA}$	I —	0.61	_	V
	V _{F (2)}	$I_{ m F}=10~{ m mA}$	_	0.74	_	
	$V_{F(3)}$	$I_{ m F}=100{ m mA}$	—	0.92	1.20	
Reverse Current $ \frac{I_{R(1)}}{I_{R(2)}} $	I _{R (1)}	$V_R = 30 V$	_		0.1	μ A
	I _{R (2)}	$V_R = 80 V$	_	_	0.5	
Total Capacitance	C_{T}	$V_{R} = 0$, $f = 1 MHz$	_	2.2	4.0	pF
Reverse Recovery Time	$\mathbf{f_T}$	$I_{F}=10\text{mA}$ (Fig.1)	_	1.6	4.0	ns

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